Surface pattern and scaling study using lattice gas models

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Motivation

In nanotechnologies large areas of **nanopatterns** are needed, which can be fabricated today only by expensive techniques, e.g. electron beam lithography or direct writing with electron and ion beams.





65 billion nanodots per square cm

Silicon Nanowire Diameter <100nm

Top-down Versus Bottom-up approach



Similar results can be obtained through bottom-up and top-down processes

Future of Top-down and Bottom-Up Processing



http://www.imec.be/wwwinter/business/nanotechnology.pdf

Fundamental theoretical understanding of the ion-beaminduced surface patterning and scaling is needed !

The Kardar-Parisi-Zhang (KPZ) equation/classes

 $\partial_t h(\mathbf{x},t) = v + \sigma \nabla^2 h(\mathbf{x},t) + \lambda (\nabla h(\mathbf{x},t))^2 + \eta(\mathbf{x},t)$

- v, λ : mean and local growth velocity
- σ : (smoothing) surface tension coefficient
- η : roughens the surface by a zero-average Gaussian noise field:

 $<\eta(x,t)\eta(x',t')> = 2 D \delta^d (x-x')(t-t')$

Up-down symmetrical case: $\lambda = 0$: Edwards-Wikinson (EW) equation/classes

The KPZ equation is nonlinear, but exhibits a tilting symmetry as the result of the Galilean invariance:

$$h \to h' + \epsilon \mathbf{x}, \qquad \mathbf{x} \to \mathbf{x}' - \lambda \epsilon t, \qquad t \to t'$$
 (7.26)

where ϵ is an infinitesimal angle. As a consequence the scaling relation

$$\tilde{\alpha} + Z = 2 \tag{7.27}$$

The Kardar-Parisi-Zhang (KPZ) equation/classes

Exactly solvable in 1+1 *d* but, in higher dimension even field theory failed due to not being able to access the strong coulping regime:



FIG. 1. Schematic phase diagram of the KPZ equation from the one-loop RG analysis. Transitions are marked by thick lines. Table 7.2 Scaling exponents of KPZ classes.

| d | $\tilde{\alpha}$ | \tilde{eta} | Z |
|---|------------------|---------------|------|
| 1 | 1/2 | 1/3 | 3/2 |
| 2 | 0.38 | 0.24 | 1.58 |
| 3 | 0.30 | 0.18 | 1.66 |

The upper critical dimension is still debated: $d_c = 2, 4, ... \infty$? 2-dim numerical estimates have a spread: $\alpha = 0.36 - 0.4$ Field theoretical conjecture by Lässig : $\alpha = 2/5$

Mappings of KPZ onto lattice gas system in 1d



Kawasaki exchange of particles

•Mapping of the *1*+*1* dimensional surface growth onto the 1d *ASEP* model.

•Surface attachment (with probability *p*) and detachment (with probability *q*) corresponds to anisotropic diffusion of particles (bullets) along the *1d* base space (*M. Plischke, Rácz and Liu, PRB 35, 3485 (1987*)

One of the simplest DDS is the one-species, asymmetric simple exclusion process (ASEP) (see Fig. 3.1). This is a site restricted, RD model with



Fig. 3.1 Dynamics of the ASEP with particle injection (rate $\tilde{\alpha}$) at the left and removal (rate $\tilde{\beta}$) at the right boundary.

The simple *ASEP* is exactly soved and many features (response to disorder, different boundary conditions ...) are known.

Driven Ising Lattice Gas invented twenty five years ago (*Katz,Lebowitz,Sphon*)

- Take the well-known equilibrium Ising system
- Drive it far from thermal equilibrium...... (by some additional external force, so particles suffer *biased* diffusion.)



Broken detailed balance condition:
 R(C → C') / R(C' → C) ≠ exp[{H(C') -H(C)}/kT]
 Stationary distribution, P*(C), exists...
 ...but very different from Boltzmann

Driven Ising Lattice Gas Steady state onfigurations



Phys. Rev. B 46 (1992) 11 432.

Mappings of KPZ growth in 2+1 dimensions



FIG. 2: (Color online) Mapping of the 2 + 1 dimensional surface growth onto the 2d particle model (bullets). Surface attachment (with probability p) and detachment (with probability q) corresponds to Kawasaki exchanges of particles, or to anisotropic diffusion of dimers in the bisectrix direction of the x and y axes. The crossing points of dashed lines show the base sub-lattice to be updated. Thick solid/dashed lines on the surface show the x/y cross-sections, corresponding to the 1d model (Fig. 1.)

 $W^{2}(t) = 0.152 \ln(t) + b$ for $t < t_{sat}$ $W^{2}(L) = 0.304 \ln(L) + d$ for $t > t_{sat}$ • Generalized Kawasaki update:

$$\begin{pmatrix} -1 & 1 \\ -1 & 1 \end{pmatrix} \rightleftharpoons \begin{pmatrix} 1 & -1 \\ 1 & -1 \end{pmatrix}$$

- Octahedron model ~ Generalized ASEP: Driven diffusive gas of pairs (dimers) (G. Ódor, B. Liedke and K.-H. Heinig, PRE79, 021125 (2009))
- For *p*=*q*=1 Edwards-Wilkinson (EW) scaling:



KPZ scaling



- For p=1, q=0 KPZ scaling: $W(t) \sim t^{0.245(5)}$ for $t < t_{sat}$ $W(L) \sim L^{0.395(5)}$ for $t > t_{sat}$
- Conciliation with the field theoretical prediction by Lassig: $\beta = 1/4$, $\alpha = 4/10$, z = 1.6
- The *P*(*W*²) distribution agrees with that of *Marinari et al.*:



In higher dimensions

- Effective, bit-coded simulations of driven Ising-like lattices
 Precise numerical estimates on large size lattices
- Generalization of the rooftop (octahedron) model in higher dimensions (3,4,5) is done (64⁵ sized lattices!)
- In *d* dimensions: *KPZ* ~ spatially anisotropic, driven random walk of oriented *d*-mers \Rightarrow Topological exclusion effects make them nontrivial
- Upper-critical dimension: Irrelavancy of topological constraints above a finite d_c?
- G.Ó, B.L, K.H: arXiv:0907.3297



Pattern formation with the octrahedron model

Competing KPZ and surface diffusion :





Noisy **Kuramoto-Sivashinsky** equation (KPZ + Mullins Diffusion):

 $\partial_{\mathbf{h}}(\mathbf{x},t) = \mathbf{v} + \sigma \nabla^2 \mathbf{h}(\mathbf{x},t) + \lambda (\nabla \mathbf{h}(\mathbf{x},t))^2 + \mathcal{K} \nabla^4 \mathbf{h}(\mathbf{h},\mathbf{x}) + \eta(\mathbf{x},t)$

To generate patterns inverse (uphill) diffusion is needed !

Realizing the (inverse) Mullins diffusion

 The pure octahedron MH model realization freezes after intervals of maximal slopes (l_d) is achieved



Patterns generated

Anisotropic surface diffusion

10KMCS

30KMCS

Coarsening ripples ^{sputtering periodicity} Wavelength growth (scaling) ?

Figure 1 A silicon surface after 500 eV Ar+ sputtering under 67°. The ripples have a periodicity of 35 nm and a height of 2 nm.

Experiment

Wavelength growth, inv.MH + KPZ \Rightarrow KPZ Anisotropic diffusion

The wavelenght (defined as longest uniform inteval) grows as:



 However if the deposition is strong (p=1) we get AKPZ ~ KPZ scaling back



Wavelength, inv.MH + KPZ \Rightarrow KPZ ?

Isotropic diffusion

 The wavelenght (defined as longest uniform inteval) saturates quickly :



- For strong diffusion (D=1) we get (KPZ ??) scaling
- For weak diffusion (D=0.1) we get KPZ scaling



 $\alpha = 5/9, \beta = 1/3, z = 5/3$ for L<1024

Patterns generated

Isotropic surface diffusion

1KMCS

10KMCS

Experiment



Coarsening dots

Figure 2 A GaSb surface after normal 500 eV Ar+ sputtering. The periodicity and the height of the dots are both 30 nm.

KPZ + Mullins = KS scaling study 1.

- For weak diffusions: *KS* ~ *KPZ scaling* In agreement with field theoretical conjecture for low dimensions *(Cuerno & Lauritsen '95)*
- Wavelenght (defined as longest uniform inteval) saturates quickly to $\lambda_{max} \sim W^2$





KPZ + Mullins = KS scaling study 2.

- For strong diffusions: Smooth surface Logarithmic growth, but not EW coefficients (a=0.04 ↔ 0.151)
- Wavelenght (defined as longest uniform inteval) saturates quickly to λ ~ 0.001*L





Summary

Mullins diffusion + KPZ growth

inv.-ADinv.-Dnormal-Dstrong-dep.weak-dep.strong-Dweak-Dstrong-DKPZMBEKPZ?KPZEWKPZripplesdots \cdot \cdot \cdot

- Precise numerical results for EW, KPZ, KS universality scaling
- Understanding of surface growth phenomena via driven lattice gases
- Efficient method to explore scaling and pattern formation
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